

Philips Semiconductors B.V.

Gerstweg 2, 6534 AE Nijmegen, The Netherlands

Report nr. : RNR-45-98-B-0827
Author : Haris Duric & Robert Cloudt
Date : 16 December 1998
Department : DSC-N, Development

CDMA CELLULAR VCO WITH THE BFG425W, BFG410W AND VARACTOR BB142

Abstract:

This application note contains an example of a Voltage Controlled Oscillator for cellular CDMA applications with the fifth generation BFG425W and BFG410W Double Poly RF-transistors. The BB142 is a new varactor specially designed for RF-application with low noise performance. The VCO is designed for the receive band of the IS-95 standard.

Appendix I: Schematic of the circuit

Appendix II: Printlayout and list of used components & materials

Appendix III: Results of measurements

Philips Semiconductors B.V.

Introduction:

With the new Philips silicon bipolar double poly BFG400W series, it is possible to design low phase noise VCO's for cellular and PCS frequency applications with a low current and a low supply voltage. These VCO's are well suited for the new generation low voltage high frequency wireless applications. In this note an example of such an VCO will be given. This VCO is designed for a center frequency of 881.5 MHz and a span of 25 MHz.

Designing the circuit:

The circuit is designed to show the following performance:

$V_{SUP}=2.7\text{ V}$

$I_{SUP}=7.3\text{mA}$

Center freq=881.5 MHz

Span = 25 MHz

Pout = 3.33 dBm

Phase noise at 60 kHz $\leq -117\text{ dBc/Hz}$

VSWRo<2:1

transistor: BFG425W, BFG410W

varactor : BB142

The output matching is realised with a LC-combination in the buffer stage. The matching circuit will also suppress the harmonics somewhat. There's a trade off between the pulling and the noise performance of the VCO.

Designing the layout:

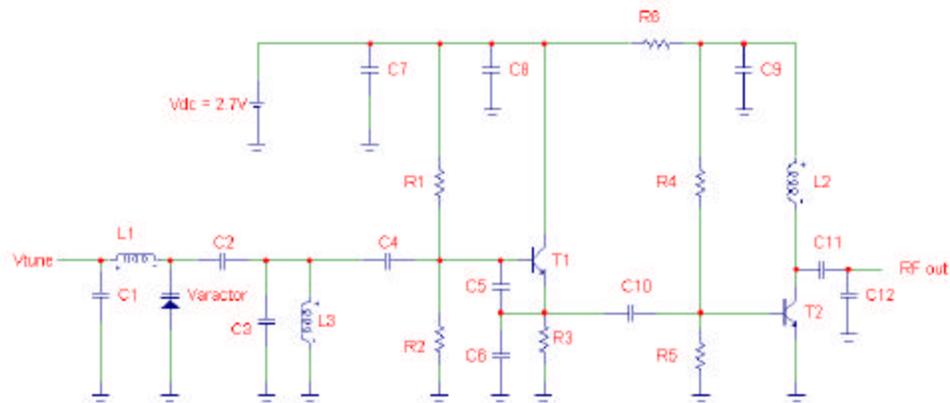
A lay-out has been designed with HP-MDS. Appendix II contains the printlayout and component placement.

Measurements:

Measurements of the total circuit (epoxy PCB) have been done. The result can be found in Appendix III.

Philips Semiconductors B.V.

Common Collector Colpitt's CDMA oscillator for the Cellular band



Appendix I: Schematic of the circuit
Figure 1:VCO circuit

CDMA VCO Component list:

Component:	Value:	Comment:
C1	47n	DC-filter
C2	3.6p	Determines tuning range
C3	4.3p	Determines tuning range
C4	56p	DC-block
C5	1.2p	Negative impedance
C6	3p	Negative impedance
C7	47n	DC-filter
C8	56p	RF-bypass
C9	56p	RF-bypass
C10	47p	match between VCO and buffer
C11	1.8p	RF-feed/output match
C12	6.8p	Output match/filter
R1	8.2k	Bias
R2	22k	Bias
R3	390	Bias
R4	2k	Bias
R5	1k	Bias
R6	100	Better RF-stability ($K > 1$)
L1	82n	RF-choke
L2	12n	Ouput match
L3	4n	Microstripline inductance for better Q
T1	BFG425W	SOT 343
T2	BFG410W	SOT 343
Varactor	BB142	SOD 523

Philips Semiconductors B.V.

Appendix II: Printlayout and list of used components & materials

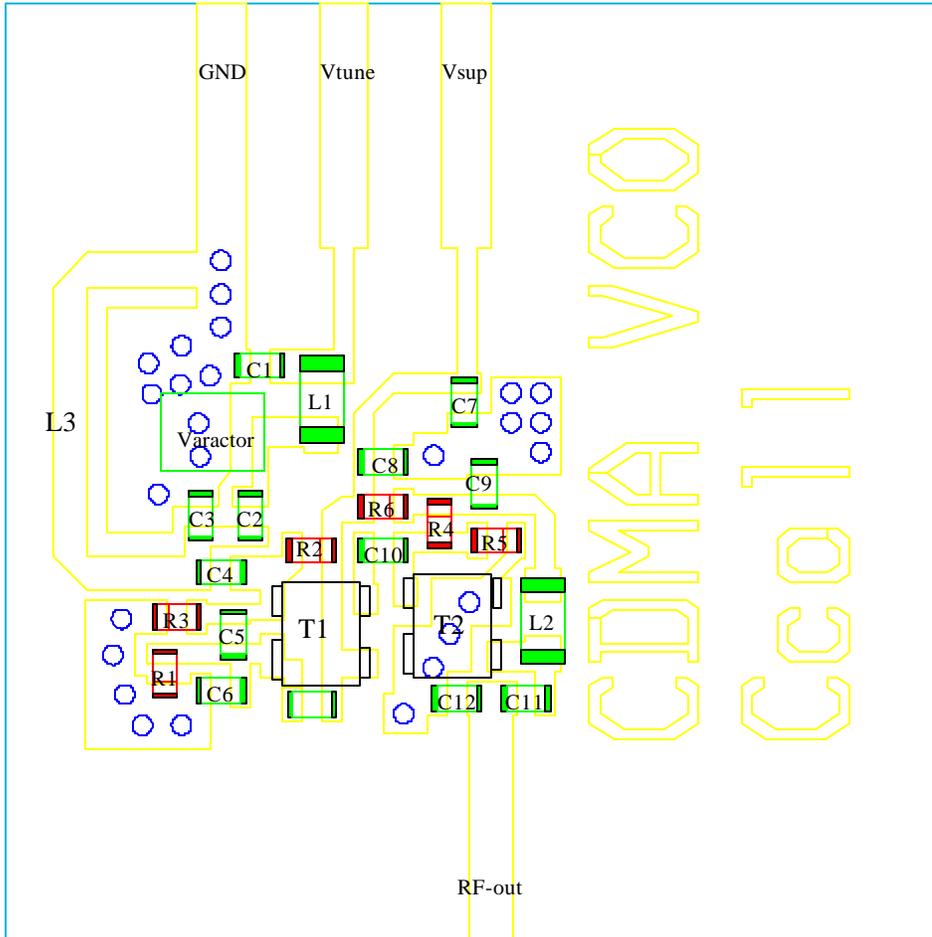


Figure 2: Printlayout

CDMA VCO Component list:

Component:	Value:	Comment:
C1	47n	0402 Philips
C2	3.6p	0402 Philips
C3	4.3p	0402 Philips
C4	56p	0402 Philips
C5	1.2p	0402 Philips
C6	3p	0402 Philips
C7	47n	0402 Philips
C8	56p	0402 Philips
C9	56p	0402 Philips
C10	47p	0402 Philips
C11	1.8p	0402 Philips
C12	6.8p	0402 Philips
R1	8.2k	0402 Philips

Philips Semiconductors B.V.

R2	22k	0402 Philips
R3	390	0402 Philips
R4	2k	0402 Philips
R5	1k	0402 Philips
R6	100	0402 Philips
L1	82n	TDK MLG 1608 SERIES
L2	12n	TDK MLG 1608 SERIES
L3	4n (W=0.7mm;L=9.6mm)	Microstrip (PCB: $\epsilon_r=4.6$,H=0.5mm)
T1	BFG425W	SOT 343
T2	BFG410W	SOT 343
Varactor	BB142	SOD523

Philips Semiconductors B.V.

Appendix III: Results of measurements:

Samples CDMA VCO's		
Specification	Unit	Value
Vcc	Volt	2.7
Power Consumption	\leq mA	7.3
Control Voltage range Min.	Volt	0
Control Voltage range Max.	Volt	2.5
Operating f range Min.	MHz	849
Operating f range Max.	MHz	900
Modulation sensitivity	MHz/V	17
Output Level	\geq dBm	3.33
Output level deviation	(+/-dBm)	0.17
C/N	\leq dBc	-75
Phase Noise(15KHz)	\leq dBc/Hz	-105
Phase Noise(30KHz)	\leq dBc/Hz	-111
Phase Noise(60KHz)	\leq dBc/Hz	-117
Pushing figure (Vcc +/-0.3V)	(+/-KHz)	400
Pulling figure (VSWR=2.0 for all phase, ref:50Ohm)	(+/-KHz)	500
Spurious response (Harmonics)	\leq dBc	-25
VSWRo		1.8
Oscillation guaranteed for VCC =	Volt	2.4<Volt<3
Width (mm)		10.25
Length (mm)		10.1

SUNSTAR 商斯达实业集团是集研发、生产、工程、销售、代理经销、技术咨询、信息服务等为一体的高科技企业，是专业高科技电子产品生产厂家，是具有 10 多年历史的专业电子元器件供应商，是中国最早和最大的仓储式连锁规模经营大型综合电子零部件代理分销商之一，是一家专业代理和分销世界各大品牌 IC 芯片和电子元器件的连锁经营综合性国际公司，专业经营进口、国产名厂名牌电子元件，型号、种类齐全。在香港、北京、深圳、上海、西安、成都等全国主要电子市场设有直属分公司和产品展示展销窗口门市部专卖店及代理分销商，已在全国范围内建成强大统一的供货和代理分销网络。我们专业代理经销、开发生产电子元器件、集成电路、传感器、微波光电元器件、工控机/DOC/DOM 电子盘、专用电路、单片机开发、MCU/DSP/ARM/FPGA 软件硬件、二极管、三极管、模块等，是您可靠的一站式现货配套供应商、方案提供商、部件功能模块开发配套商。商斯达实业公司拥有庞大的资料库，有数位毕业于著名高校——有中国电子工业摇篮之称的西安电子科技大学（西军电）并长期从事国防尖端科技研究的高级工程师为您精挑细选、量身订做各种高科技电子元器件，并解决各种技术问题。

微波光电部专业代理经销高频、微波、光纤、光电元器件、组件、部件、模块、整机；电磁兼容元器件、材料、设备；微波 CAD、EDA 软件、开发测试仿真工具；微波、光纤仪器仪表。欢迎国外高科技微波、光纤厂商将优秀产品介绍到中国、共同开拓市场。长期大量现货专业批发高频、微波、卫星、光纤、电视、CATV 器件：晶振、VCO、连接器、PIN 开关、变容二极管、开关二极管、低噪晶体管、功率电阻及电容、放大器、功率管、MMIC、混频器、耦合器、功分器、振荡器、合成器、衰减器、滤波器、隔离器、环行器、移相器、调制解调器；光电子元件和组件：红外发射管、红外接收管、光电开关、光敏管、发光二极管和发光二极管组件、半导体激光二极管和激光器组件、光电探测器和光接收组件、光发射接收模块、光纤激光器和光放大器、光调制器、光开关、DWDM 用光发射和接收器件、用户接入系统光收发器件与模块、光纤连接器、光纤跳线/尾纤、光衰减器、光纤适配器、光隔离器、光耦合器、光环行器、光复用器/转换器；无线收发芯片和模组、蓝牙芯片和模组。

更多产品请看本公司产品专用销售网站：

商斯达中国传感器科技信息网：<http://www.sensor-ic.com/>

商斯达工控安防网：<http://www.pc-ps.net/>

商斯达电子元器件网：<http://www.sunstare.com/>

商斯达微波光电产品网：[HTTP://www.rfoe.net/](http://www.rfoe.net/)

商斯达消费电子产品网：<http://www.icasic.com/>

商斯达实业科技产品网：<http://www.sunstars.cn/> 微波元器件销售热线：

地址：深圳市福田区福华路福庆街鸿图大厦 1602 室

电话：0755-82884100 83397033 83396822 83398585

传真：0755-83376182 (0) 13823648918 MSN: SUNS8888@hotmail.com

邮编：518033 E-mail:szss20@163.com QQ: 195847376

深圳赛格展销部：深圳华强北路赛格电子市场 2583 号 电话：0755-83665529 25059422

技术支持：0755-83394033 13501568376

欢迎索取免费详细资料、设计指南和光盘；产品凡多，未能尽录，欢迎来电查询。

北京分公司：北京海淀区知春路 132 号中发电子大厦 3097 号

TEL: 010-81159046 82615020 13501189838 FAX: 010-62543996

上海分公司：上海市北京东路 668 号上海赛格电子市场 D125 号

TEL: 021-28311762 56703037 13701955389 FAX: 021-56703037

西安分公司：西安高新开发区 20 所(中国电子科技集团导航技术研究所)

西安劳动南路 88 号电子商城二楼 D23 号

TEL: 029-81022619 13072977981 FAX:029-88789382